

PNP General Purpose Transistor

BC858BW / BC858B

●Features

- 1) $BV_{CEO} < -30V$ ($I_C = -1mA$)
- 2) Complements the BC848B / BC848BW.

●Package, marking and packaging specifications

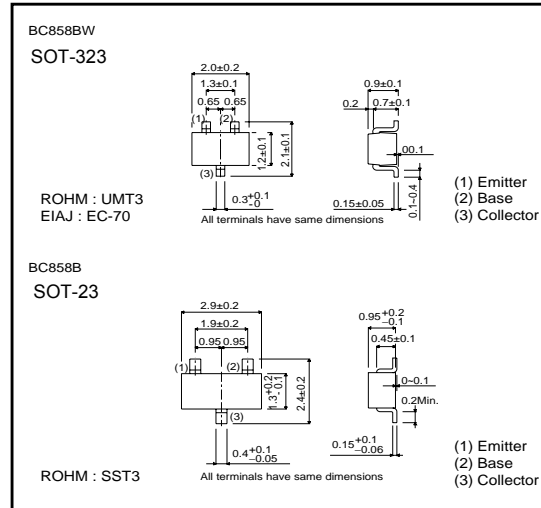
Part No.	BC858BW	BC858B
Packaging type	UMT3	SST3
Marking	G3K	G3K
Code	T106	T116
Basic ordering unit (pieces)	3000	3000

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V_{CEO}	-30	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-0.1	A
Collector power dissipation	P_C	0.2	W *
		0.35	
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-65 to +150	°C

* When mounted on 7 × 5 × 0.6 mm ceramic board.

●External dimensions (Unit : mm)



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	-30	-	-	V	$I_C = -50\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	-30	-	-	V	$I_C = -1mA$
Emitter-base breakdown voltage	BV_{EBO}	-5	-	-	V	$I_E = -50\mu A$
Collector cutoff current	I_{CBO}	-	-	-100	nA	$V_{CB} = -30V$
		-	-	4	μA	$V_{CB} = -30V, T_a = 150^\circ C$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	-0.3	V	$I_C/I_B = -10mA/-0.5mA$
		-	-	-0.65	V	$I_C/I_B = -100mA/-5mA$
Base-emitter saturation voltage	$V_{BE(on)}$	-0.6	-	-0.75	V	$V_{CE}/I_C = -5V/-10mA$
DC current transfer ratio	h_{FE}	210	-	480	-	$V_{CE}/I_C = -5V/-2mA$
Transition frequency	f_T	-	250	-	MHz	$V_{CE} = -5V, I_E = 20mA, f = 100MHz$
Output capacitance	C_{ob}	-	4.5	-	pF	$V_{CB} = -10V, I_E = 0, f = 1MHz$

●Electrical characteristics curves

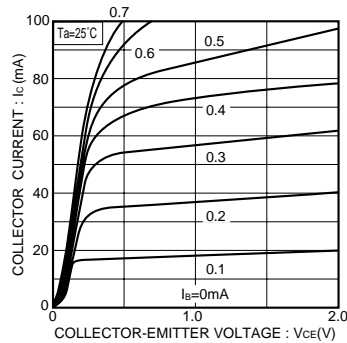


Fig.1 Grounded emitter output characteristics (I)

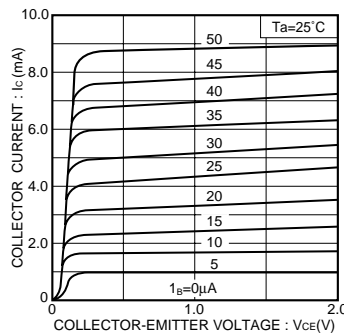


Fig.2 Grounded emitter output characteristics (II)

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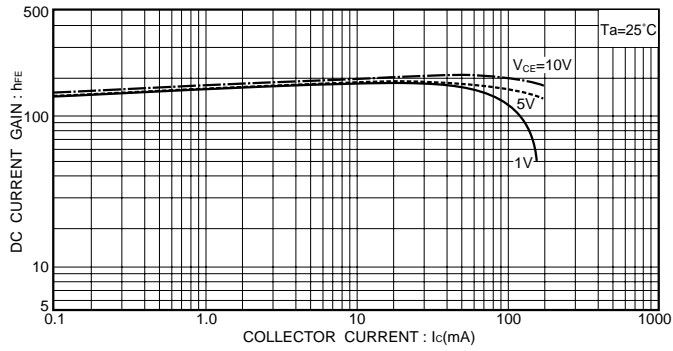


Fig.3 DC current gain vs. collector current (I)

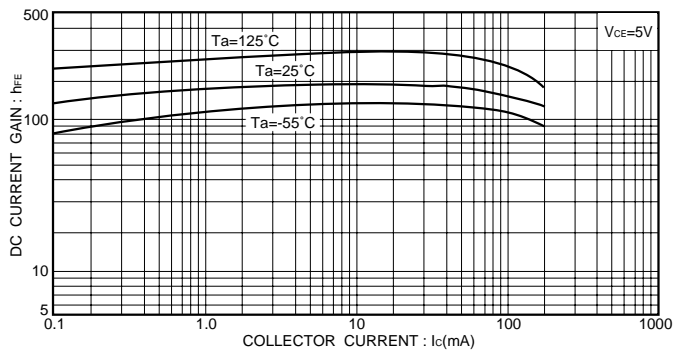


Fig.4 DC current gain vs. collector current (II)

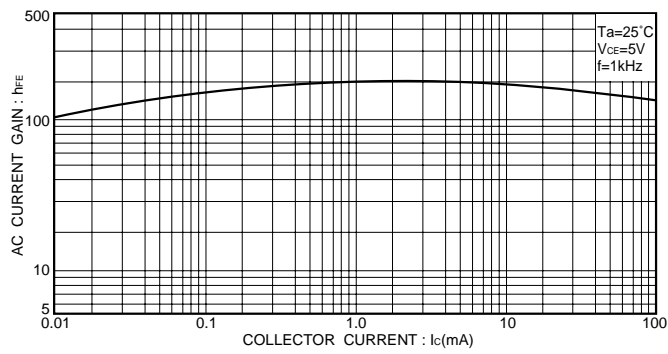


Fig.5 AC current gain vs. collector current

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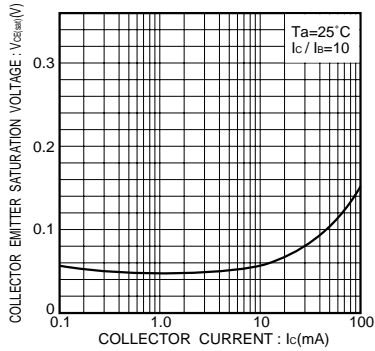


Fig.6 Collector-emitter saturation voltage vs. collector current

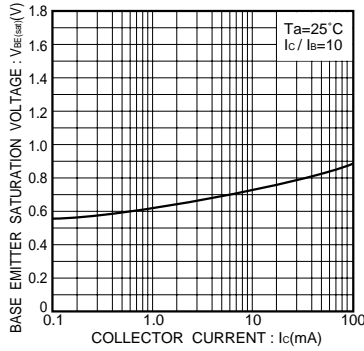


Fig.7 Base-emitter saturation voltage vs. collector current

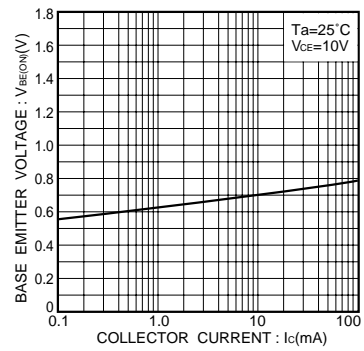


Fig.8 Grounded emitter propagation characteristics

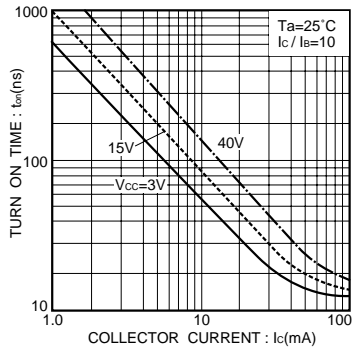


Fig.9 Turn-on time vs. collector current

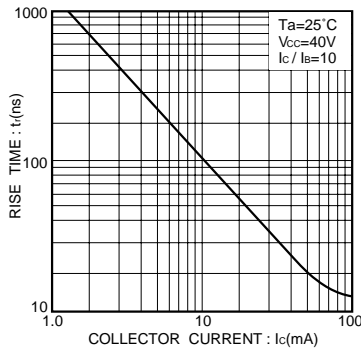


Fig.10 Rise time vs. collector current

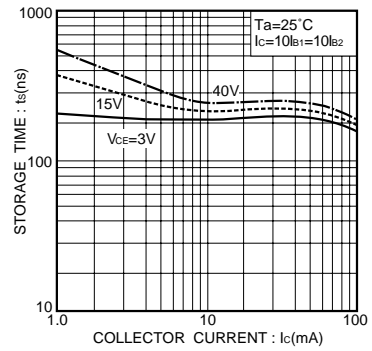


Fig.11 Storage time vs. collector current

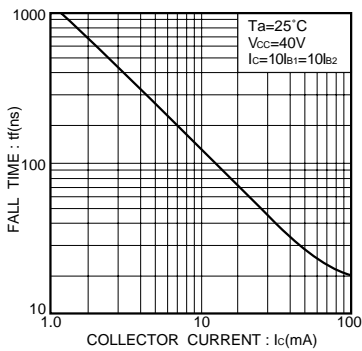


Fig.12 Fall time vs. collector current

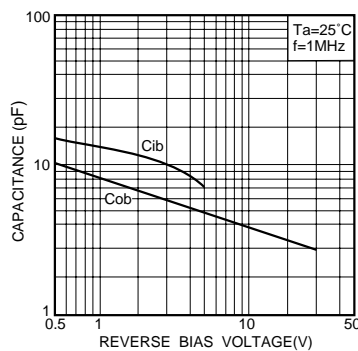


Fig.13 Input/output capacitance vs. voltage

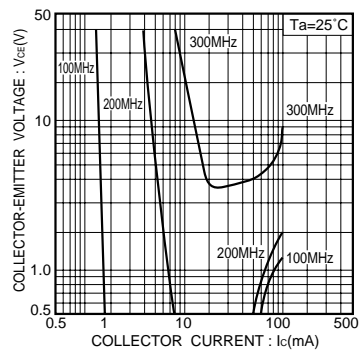


Fig.14 Gain bandwidth product

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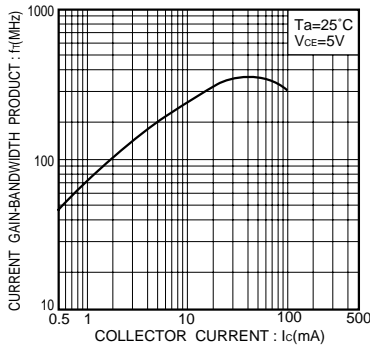


Fig.15 Gain bandwidth product vs. collector current

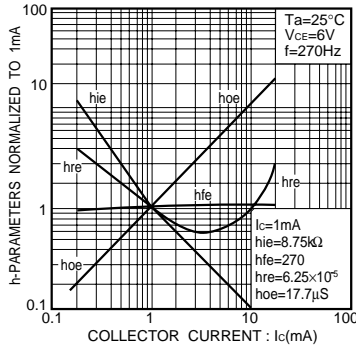


Fig.16 h parameter vs. collector current

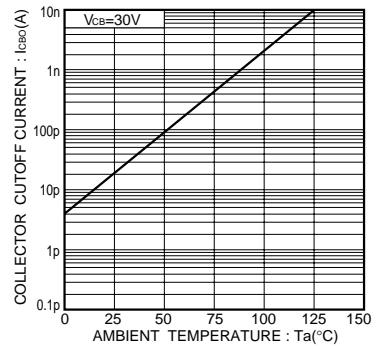


Fig.17 Noise characteristics (I)

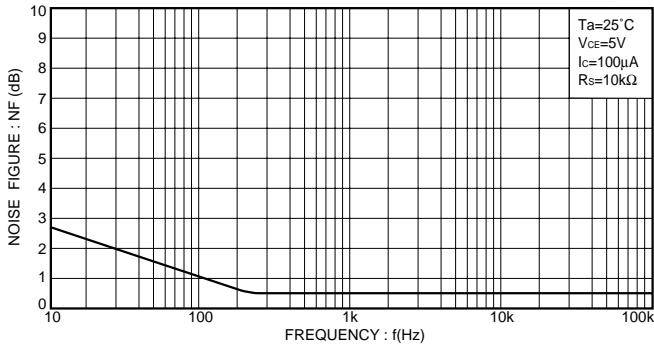


Fig.18 Noise vs. collector current

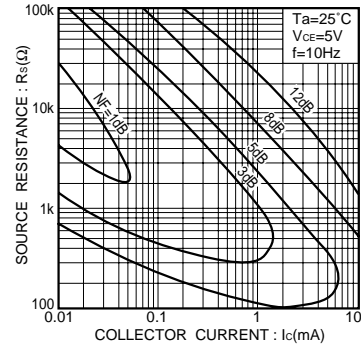


Fig.19 Noise characteristics (II)

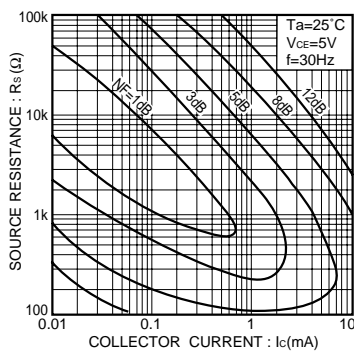


Fig.20 Noise characteristics (III)

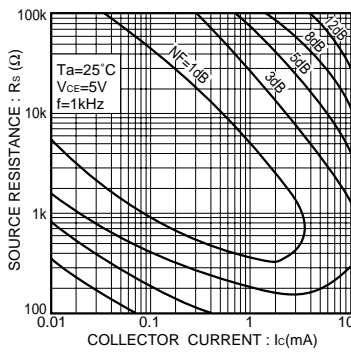


Fig.21 Noise characteristics (IV)

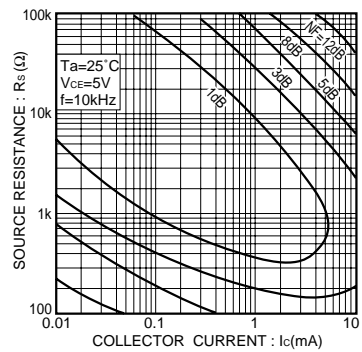


Fig.22 Noise characteristics (V)

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